

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MZ540FK

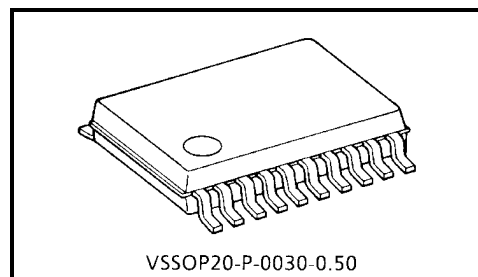
Low Voltage Octal Bus Buffer (inverted) with 5 V Tolerant Inputs and Outputs

The TC7MZ540FK is a high performance CMOS octal bus buffer. Designed for use in 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The TC7MZ540FK is an inverting 3-state buffer having two active-low output enables. When either  $\overline{OE}1$  or  $\overline{OE}2$  are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.



VSSOP20-P-0030-0.50

Weight: 0.03 g (typ.)

## Features

- Low voltage operation:  $V_{CC} = 2.0 \sim 3.6$  V
- High speed operation:  $t_{pd} = 6.5$  ns (max) ( $V_{CC} = 3.0 \sim 3.6$  V)
- Output current:  $|I_{OH}|/I_{OL} = 24$  mA (min) ( $V_{CC} = 3.0$  V)
- Latch-up performance:  $\pm 500$  mA
- Package: VSSOP (US20)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 540 type.

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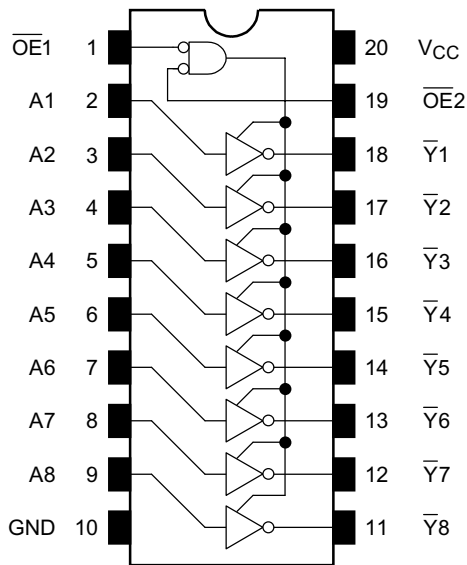
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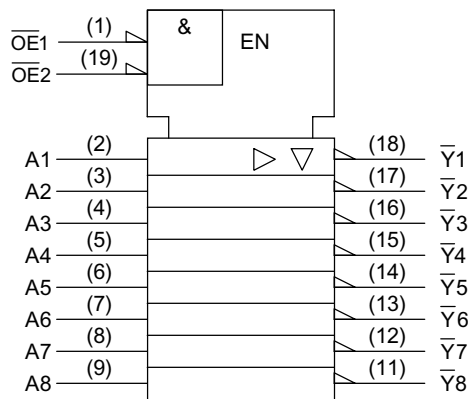
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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs			Outputs
OE1	OE2	A <sub>n</sub>	
H	X	X	Z
X	H	X	Z
L	L	H	L
L	L	L	H

X: Don't care

Z: High impedance

Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~7.0	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5~7.0 (Note1)	V
		-0.5~V <sub>CC</sub> + 0.5 (Note2)	
Input diode current	I <sub>IK</sub>	-50	mA
Output diode current	I <sub>OK</sub>	±50 (Note3)	mA
DC output current	I <sub>OUT</sub>	±50	mA
Power dissipation	P <sub>D</sub>	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note1: Output in off-state

Note2: High or low state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note3: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

## Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2.0~3.6	V
		1.5~3.6 (Note4)	
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~5.5 (Note5)	V
		0~ $V_{CC}$ (Note6)	
Output current	$I_{OH}/I_{OL}$	$\pm 24$ (Note7)	mA
		$\pm 12$ (Note8)	
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note9)	ns/V

Note4: Data retention only

Note5: Output in off-state

Note6: High or low state

Note7:  $V_{CC} = 3.0\sim 3.6$  VNote8:  $V_{CC} = 2.7\sim 3.0$  VNote9:  $V_{IN} = 0.8\sim 2.0$  V,  $V_{CC} = 3.0$  V

## Electrical Characteristics

DC Characteristics ( $T_a = -40\sim 85^\circ\text{C}$ )

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	High level	V <sub>IH</sub>	—		2.7~3.6	2.0	—	V
	Low level	V <sub>IL</sub>	—		2.7~3.6	—	0.8	
Output voltage	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7~3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -12 mA	2.7	2.2	—	
				I <sub>OH</sub> = -18 mA	3.0	2.4	—	
				I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7~3.6	—	0.2	
				I <sub>OL</sub> = 12 mA	2.7	—	0.4	
				I <sub>OL</sub> = 16 mA	3.0	—	0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5 V		2.7~3.6	—	±5.0	μA
3-state output off-state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~5.5 V		2.7~3.6	—	±5.0	μA
Power off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7~3.6	—	10.0	μA
			V <sub>IN</sub> /V <sub>OUT</sub> = 3.6~5.5 V		2.7~3.6	—	±10.0	
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.7~3.6	—	500	

## AC Characteristics (Ta = -40~85°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	—	7.5	ns
	t <sub>pHL</sub>		3.3 ± 0.3	1.5	6.5	
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	2.7	—	9.5	ns
	t <sub>pZH</sub>		3.3 ± 0.3	1.5	8.5	
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	2.7	—	8.5	ns
	t <sub>pHZ</sub>		3.3 ± 0.3	1.5	7.5	
Output to output skew	t <sub>osLH</sub>	(Note10)	2.7	—	—	ns
	t <sub>osHL</sub>		3.3 ± 0.3	—	1.0	

Note10: This parameter is guaranteed by design.

(t<sub>osLH</sub> = |t<sub>pLHm</sub> - t<sub>pLHn</sub>|, t<sub>osHL</sub> = |t<sub>pHLm</sub> - t<sub>pHLn</sub>|)

## Dynamic Switching Characteristics

(Ta = 25°C, Input: t<sub>r</sub> = t<sub>f</sub> = 2.5 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 Ω)

Characteristics	Symbol	Test Condition		Typ.	Unit	
			V <sub>CC</sub> (V)			
Quiet output maximum dynamic	V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V
Quiet output minimum dynamic	V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V

## Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Unit
Input capacitance	C <sub>IN</sub>	—	3.3	7	pF
Output capacitance	C <sub>OUT</sub>	—	3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note11)	3.3	40	pF

Note11: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

AC Test Circuit

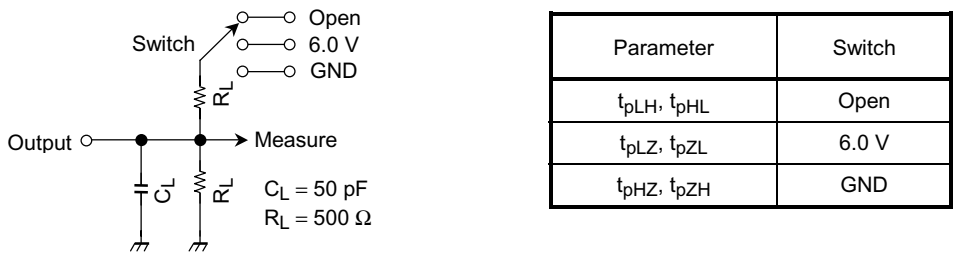


Figure 1

AC Waveform

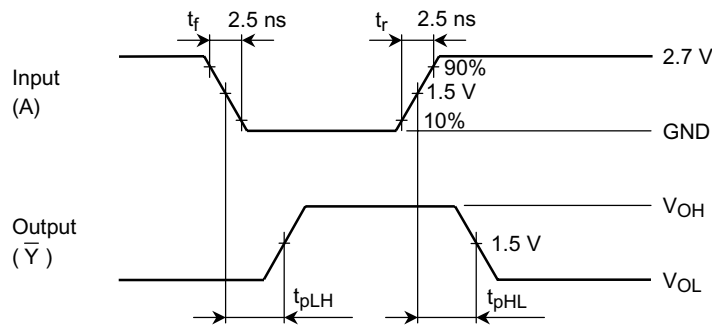


Figure 2  $t_{pLH}$ ,  $t_{pHL}$

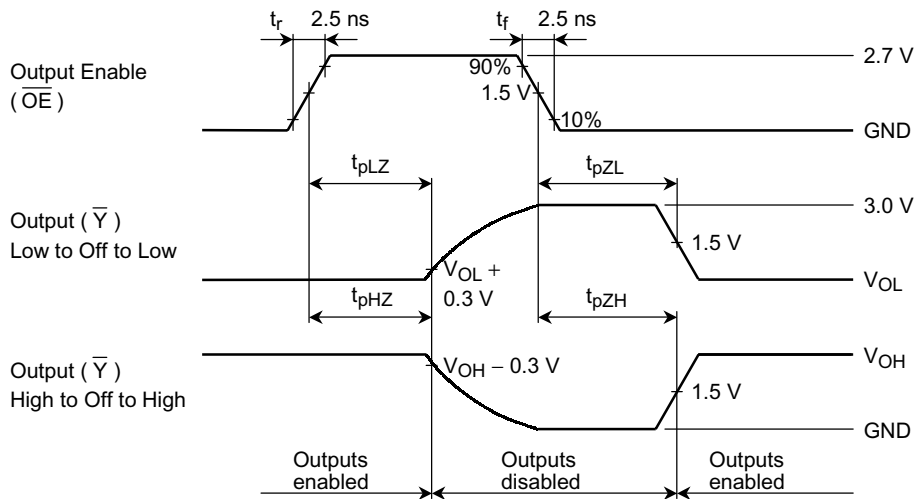
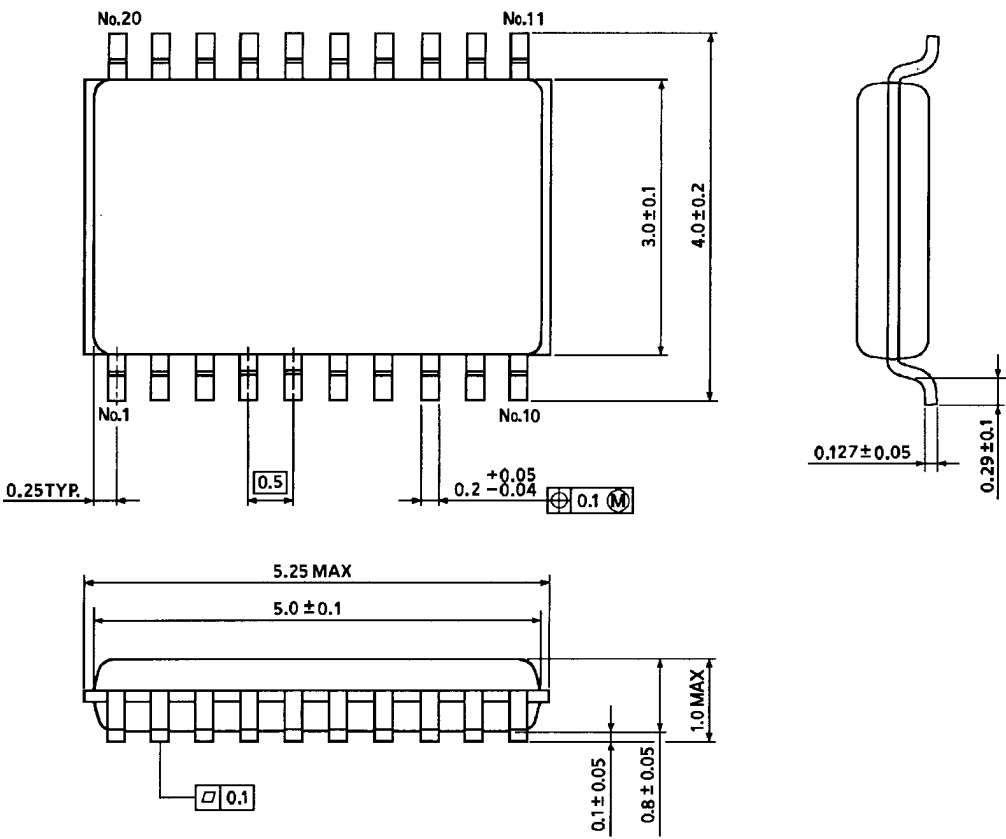


Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$

Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)